# PDTA123T series

PNP resistor-equipped transistors; R1 = 2.2 k $\Omega$ , R2 = open

Rev. 02 — 3 September 2009

**Product data sheet** 

## 1. Product profile

### 1.1 General description

PNP Resistor-Equipped Transistors (RET) family.

Table 1. Product overview

Type number	Package	Package			
	NXP	JEITA	JEDEC		
PDTA123TE	SOT416	SC-75	-	PDTC123TE	
PDTA123TK	SOT346	SC-59A	TO-236	PDTC123TK	
PDTA123TM	SOT883	SC-101	-	PDTC123TM	
PDTA123TS[1]	SOT54	SC-43A	TO-92	PDTC123TS	
PDTA123TT	SOT23	-	TO-236AB	PDTC123TT	
PDTA123TU	SOT323	SC-70	-	PDTC123TU	

<sup>[1]</sup> Also available in SOT54A and SOT54 variant packages (see Section 2)

### 1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- 100 mA output current capability
- Reduces component count
- Reduces pick and place costs

### 1.3 Applications

- Digital applications
- Controlling IC inputs

- Cost-saving alternative for BC857 series in digital applications
- Switching loads

#### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	-50	V
I <sub>O</sub>	output current		-	-	-100	mA
R1	bias resistor 1 (input)		1.54	2.2	2.86	$k\Omega$



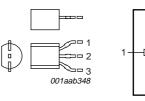
# 2. Pinning information

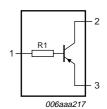
Table 3. Pinning

Pin	Description	Simplified outline	Symbol
SOT54			
1	input (base)		
2	output (collector)		2
3	GND (emitter)	001aab347	1 R1 3 006aaa217

007	FF 4 A
SO	1544

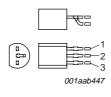
1	input (base)	
2	output (collector)	
3	GND (emitter)	

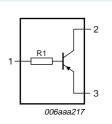




### SOT54 variant

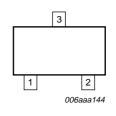
1	input (base)
2	output (collector)
3	GND (emitter)

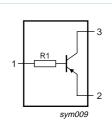




### SOT23; SOT323; SOT346; SOT416

1	input (base)
2	GND (emitter)
3	output (collector)

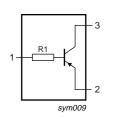




#### **SOT883**

1	input (base)
2	GND (emitter)
3	output (collector)





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# 3. Ordering information

Table 4. Ordering information

Package						
Name	Description	Version				
SC-75	plastic surface mounted package; 3 leads	SOT416				
SC-59A	plastic surface mounted package; 3 leads	SOT346				
SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 $\times$ 0.6 $\times$ 0.5 mm	SOT883				
SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54				
-	plastic surface mounted package; 3 leads	SOT23				
SC-70	plastic surface mounted package; 3 leads	SOT323				
	Name SC-75 SC-59A SC-101 SC-43A	Name Description  SC-75 plastic surface mounted package; 3 leads  SC-59A plastic surface mounted package; 3 leads  SC-101 leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm  SC-43A plastic single-ended leaded (through hole) package; 3 leads  - plastic surface mounted package; 3 leads				

<sup>[1]</sup> Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9)

## 4. Marking

Table 5. Marking codes

indicate in the second	
Type number	Marking code <sup>[1]</sup>
PDTA123TE	2A
PDTA123TK	GA
PDTA123TM	FA
PDTA123TS	TA123T
PDTA123TT	ZL*
PDTA123TU	*1S

<sup>[1] \* = -:</sup> made in Hong Kong

<sup>\* =</sup> p: made in Hong Kong

<sup>\* =</sup> t: made in Malaysia

<sup>\* =</sup> W: made in China

# 5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Mi	n Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	-50	V
$V_{CEO}$	collector-emitter voltage	open base	-	-50	V
$V_{EBO}$	emitter-base voltage	open collector	-	-5	V
lo	output current		-	-100	mA
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$			
	SOT416		<u>[1]</u> _	150	mW
	SOT346		[1] _	250	mW
	SOT883		[2][3]	250	mW
	SOT54		<u>[1]</u> _	500	mW
	SOT23		<u>[1]</u> _	250	mW
	SOT323		<u>[1]</u> -	200	mW
T <sub>stg</sub>	storage temperature		-6	5 +150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-6	5 +150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

### 6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j\text{-}a)}$	thermal resistance from junction to ambient	in free air				
	SOT416		<u>[1]</u> _	-	833	K/W
	SOT346		<u>[1]</u> _	-	500	K/W
	SOT883		[2][3]	-	500	K/W
	SOT54		<u>[1]</u> _	-	250	K/W
	SOT23		<u>[1]</u> _	-	500	K/W
	SOT323		<u>[1]</u> _	-	625	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

<sup>[3]</sup> Device mounted on an FR4 PCB with 60 µm copper strip line, standard footprint.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

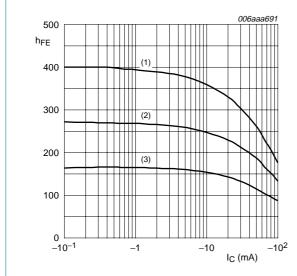
<sup>[3]</sup> Device mounted on an FR4 PCB with 60  $\mu m$  copper strip line, standard footprint.

### 7. Characteristics

Table 8. Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified

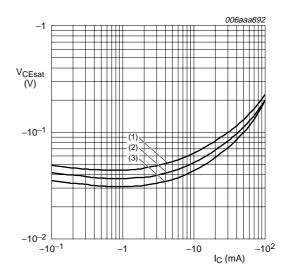
· allib =0	C arrived entermies opening					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$I_{CBO}$	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	-	-	-100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	$V_{CE} = -30 \text{ V}; I_{B} = 0 \text{ A}$	-	-	-1	μΑ
		$V_{CE} = -30 \text{ V; } I_{B} = 0 \text{ A;}$ $T_{j} = 150 \text{ °C}$	-	-	-50	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$	-	-	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -20 \text{ mA}$	30	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -10 \text{ mA}; I_B = -0.5 \text{ mA}$	-	-	-150	mV
R1	bias resistor 1 (input)		1.54	2.2	2.86	$k\Omega$
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = I_e = 0 \text{ A};$ f = 1 MHz	-	-	3	pF





- (1)  $T_{amb} = 100 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = -40 \, ^{\circ}C$

Fig 1. DC current gain as a function of collector current; typical values

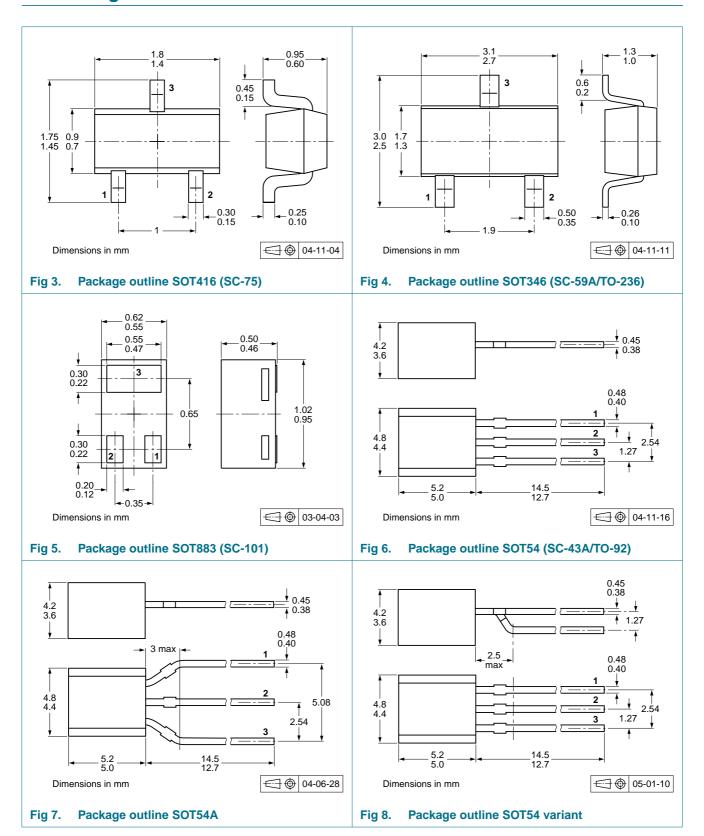


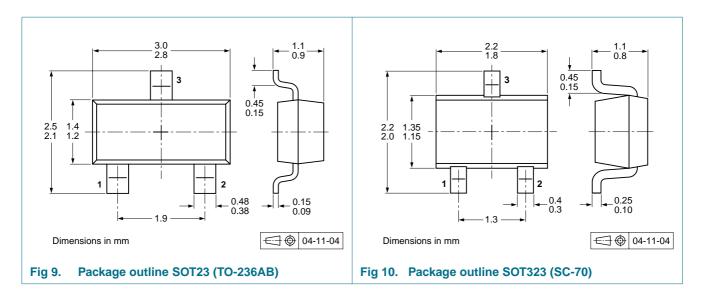
 $I_{\rm C}/I_{\rm B}=20$ 

- (1)  $T_{amb} = 100 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = -40 \, ^{\circ}C$

Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values

# 8. Package outline





# 9. Packing information

**Table 9. Packing methods**The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packin	Packing quantity		
			3000	5000	10000	
PDTA123TE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTA123TK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTA123TM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315	
PDTA123TS	SOT54	bulk, straight leads	-	-412	-	
	SOT54A SOT54 variant	tape and reel, wide pitch	-	-	-116	
		tape ammopack, wide pitch	-	-	-126	
		bulk, delta pinning	-	-112	-	
PDTA123TT	SOT23	4 mm pitch, 8 mm tape and reel	-215		-235	
PDTA123TU	SOT323	4 mm pitch, 8 mm tape and reel	-115		-135	

<sup>[1]</sup> For further information and the availability of packing methods, see Section 12.

# **PDTA123T series**

PNP resistor-equipped transistors; R1 = 2.2 kΩ, R2 = open

# 10. Revision history

### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTA123T_SER_2	20090903	Product data sheet	-	PDTA123T_SER_1
Modifications:		eet was changed to reflect w legal definitions and disc		
PDTA123T_SER_1	20060307	Product data sheet	-	-

## 11. Legal information

#### 11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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# **PDTA123T series**

PNP resistor-equipped transistors; R1 = 2.2 k $\Omega$ , R2 = open

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